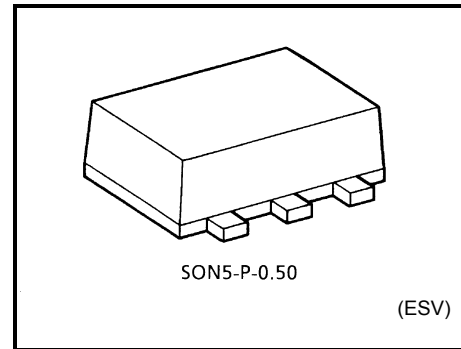


TC7SZ08AFE

2 Input AND Gate

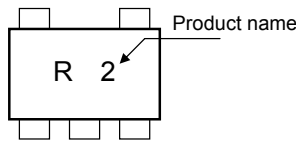
Features

- High output drive: ± 24 mA (min)
at $V_{CC} = 3$ V
- Super high speed operation: t_{pd} 2.7 ns (typ.)
at $V_{CC} = 5$ V, 50 pF
- Operation voltage range: V_{CC} (opr.) = 1.8~5.5 V
- Supply voltage data retention: $V_{CC} = 1.5$ ~5.5 V
- 5.5-V tolerant inputs
- Matches the performance of TC74LCX series when operated at 3.3 -V V_{CC}

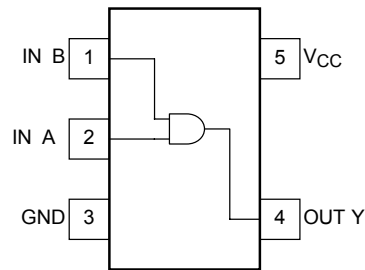


Weight: 0.003 g (typ.)

Marking



Pin Assignment (top view)



Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5~6	V
DC input voltage	V_{IN}	-0.5~6	V
DC output voltage	V_{OUT}	-0.5~ $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 50	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	150	mW
Storage temperature	T_{stg}	-65~150	°C
Lead temperature (10 s)	T_L	260	°C

Logic Diagram



Truth Table

A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	1.8~5.5	V
		1.5~5.5 (Note 1)	
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~ V_{CC}	V
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	d_t/d_v	0~20 ($V_{CC} = 1.8\text{ V}, 2.5\text{ V} \pm 0.2\text{ V}$)	ns/V
		0~10 ($V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$)	
		0~5 ($V_{CC} = 5.5\text{ V} \pm 0.5\text{ V}$)	

Note 1: Data retention only

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition	V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		Unit	
				Min	Typ.	Max	Min	Max		
High-level input voltage	V _{IH}	—	1.8	0.75 × V _{CC}	—	—	0.75 × V _{CC}	—	V	
			2.3-5.5	0.7 × V _{CC}	—	—	0.7 × V _{CC}	—		
Low-level input voltage	V _{IL}	—	1.8	—	—	0.25 × V _{CC}	—	0.25 × V _{CC}	V	
			2.3-5.5	—	—	0.3 × V _{CC}	—	0.3 × V _{CC}		
High-level output voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -100 μA	1.8	1.7	1.8	—	1.7	—	V
				2.3	2.2	2.3	—	2.2	—	
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = -8 mA	2.3	1.9	2.15	—	1.9	—	
			I _{OH} = -16 mA	3.0	2.4	2.8	—	2.4	—	
			I _{OH} = -24 mA	3.0	2.3	2.68	—	2.3	—	
I _{OH} = -32 mA	4.5	3.8	4.2	—	3.8	—				
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8	—	0	0.1	—	0.1	V
				2.3	—	0	0.1	—	0.1	
				3.0	—	0	0.1	—	0.1	
				4.5	—	0	0.1	—	0.1	
			I _{OL} = 8 mA	2.3	—	0.1	0.3	—	0.3	
			I _{OL} = 16 mA	3.0	—	0.15	0.4	—	0.4	
			I _{OL} = 24 mA	3.0	—	0.22	0.55	—	0.55	
I _{OL} = 32 mA	4.5	—	0.22	0.55	—	0.55				
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	0-5.5	—	—	±1	—	±10	μA	
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	2	—	20	μA	

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit	
			V _{CC} (V)	Min	Typ.	Max	Min		Max
Propagation delay time	t _{pLH} t _{pHL}	C _L = 15 pF, R _L = 1 MΩ	1.8	2.0	5.2	9.5	2.0	10.5	ns
			2.5 ± 0.2	0.8	3.4	7.0	0.8	7.5	
			3.3 ± 0.3	0.5	2.6	4.7	0.5	5.0	
			5.0 ± 0.5	0.5	2.2	4.1	0.5	4.4	
		C _L = 50 pF, R _L = 500 Ω	3.3 ± 0.3	1.5	3.3	5.2	1.5	5.5	
			5.0 ± 0.5	0.8	2.7	4.5	0.8	4.8	
Input capacitance	C _{IN}	—	0-5.5	—	4	—	—	—	pF
Power dissipation capacitance	C _{PD}	(Note 2)	3.3	—	19	—	—	—	pF
			5.5	—	26	—	—	—	

Note2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

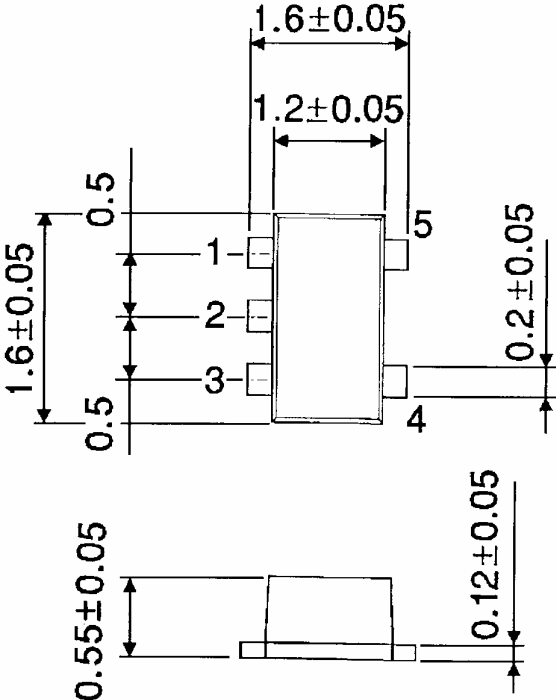
Average operating current can be obtained by the equation.

$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

SON5-P-0.50

Unit : mm



Weight: 0.003 g (typ.)

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